TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

T C 7 M H 2 7 3 F K

Octal D-Type Flip Flop with Clear

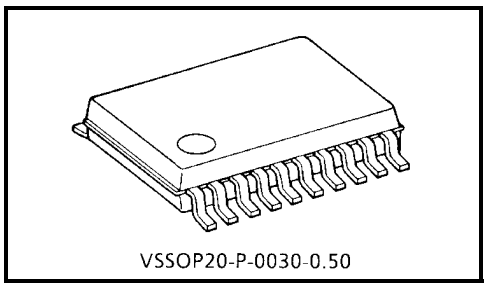
The TC7MH273FK is an advanced high speed CMOS octal D-type flip-flop fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{CLR}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.



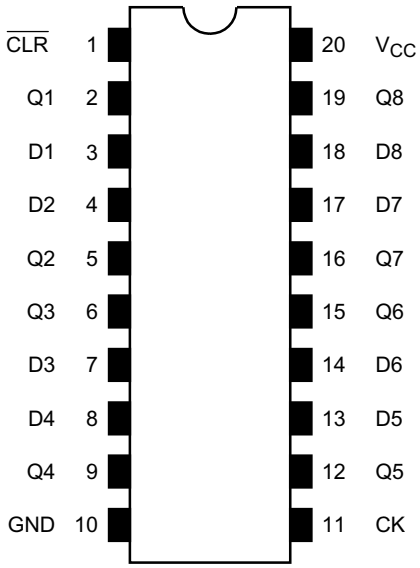
VSSOP20-P-0030-0.50

Weight: 0.03 g (typ.)

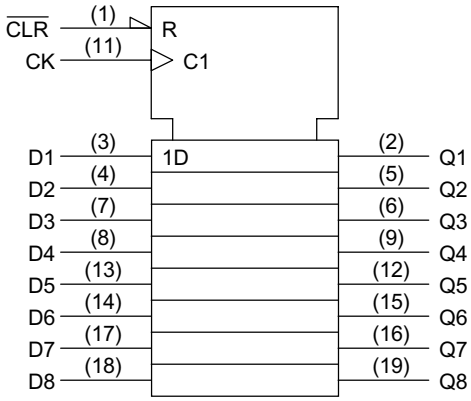
Features

- High speed: f_{max} = 165 MHz (typ.) (V_{CC} = 5 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2~5.5 V
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74ALS273

Pin Assignment (top view)



IEC Logic Symbol

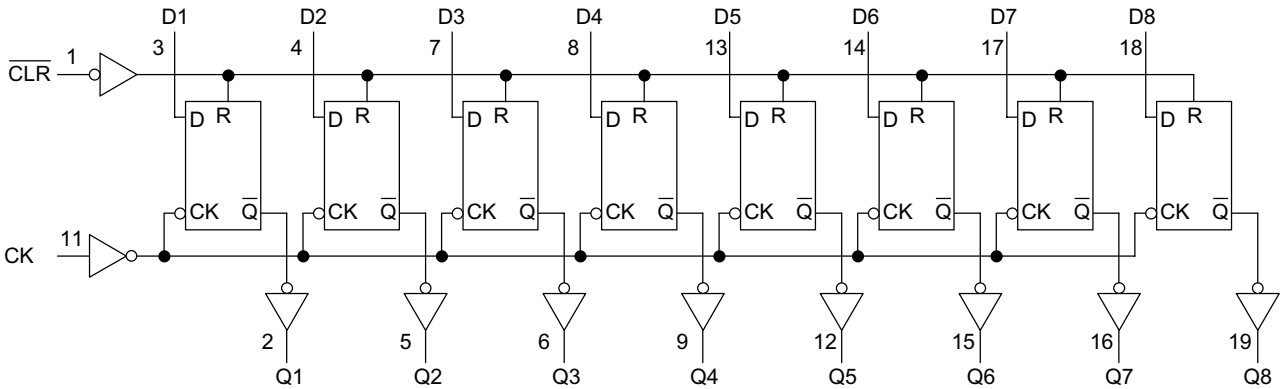


Truth Table

Inputs			Outputs	Function
$\overline{CLR}$	D	CK	Q	
L	X	X	L	Clear
H	L	↑	L	—
H	H	↑	H	—
H	X	↓	Q_n	No change

X: Don't care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 ± 0.3 V) 0~20 (V_{CC} = 5 ± 0.5 V)	ns/V

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C				Ta = −40~85°C		Unit
					V_{CC} (V)	Min	Typ.	Max	Min	Max	
Input voltage	"H" level	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
					3.0~5.5	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
	"L" level	V_{IL}	—		2.0	—	—	0.50	—	0.50	
					3.0~5.5	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
Output voltage	"H" level	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
					3.0	2.9	3.0	—	2.9	—	
					4.5	4.4	4.5	—	4.4	—	
				I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
				I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
	"L" level	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0	0.1	—	0.1	
					3.0	—	0	0.1	—	0.1	
					4.5	—	0	0.1	—	0.1	
				I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
				I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA

Timing Requirements (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = −40~85°C	Unit
			V_{CC} (V)	Typ.	Limit	Limit	
Minimum pulse width (CK)	$t_{w(L)}$ $t_{w(H)}$	—	3.3 ± 0.3	—	5.5	6.5	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum pulse width ($\overline{CLR}$)	$t_{w(L)}$	—	3.3 ± 0.3	—	5.0	6.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum set-up time	t_s	—	3.3 ± 0.3	—	5.5	6.5	ns
			5.0 ± 0.5	—	4.5	4.5	
Minimum hold time	t_h	—	3.3 ± 0.3	—	1.0	1.0	ns
			5.0 ± 0.5	—	1.0	1.0	
Minimum removal time ($\overline{CLR}$)	t_{rem}	—	3.3 ± 0.3	—	2.5	2.5	ns
			5.0 ± 0.5	—	2.0	2.0	

AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.7	13.6	1.0	16.0	ns
				50	—	11.2	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.8	9.0	1.0	10.5	
				50	—	7.3	11.0	1.0	12.5	
Propagation delay time ($\overline{CLR}$-Q)	t_{pHL}	—	3.3 ± 0.3	15	—	8.9	13.6	1.0	16.0	ns
				50	—	11.4	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.2	8.5	1.0	10.0	
				50	—	6.7	10.5	1.0	12.0	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	75	120	—	65	—	MHz
				50	50	75	—	45	—	
			5.0 ± 0.5	15	120	165	—	100	—	
				50	80	110	—	70	—	
Output to output skew	t_{osLH} t_{osHL}	(Note1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note2)			—	31	—	—	—	pF

Note1: This parameter is guaranteed by design.

$t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per F/F)

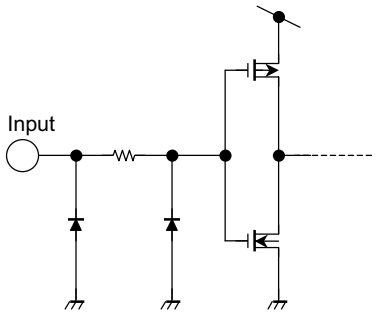
And the total C_{PD} when n pcs of flip-flop operate can be gained by the following equation:

C_{PD} (total) = 22 + 9·n

Noise Characteristics (Input: $t_r = t_f = 3$ ns)

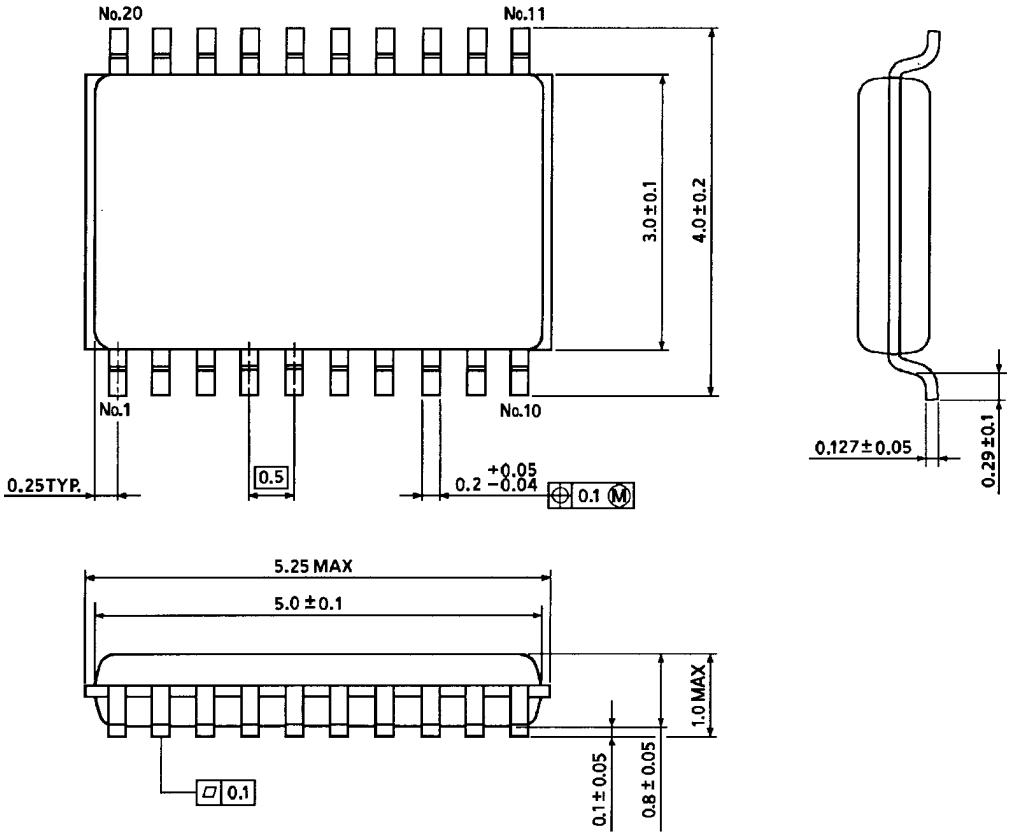
Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V_{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.5	−0.8	V
Minimum high level dynamic input voltage V_{IH}	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage V_{IL}	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit



Package Dimensions

VSSOP20-P-0030-0.50 Unit : mm



Weight: 0.03 g (typ.)